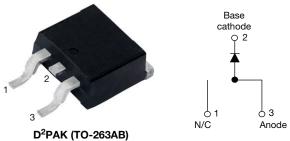
VS-6TQ035S-M3, VS-6TQ040S-M3, VS-6TQ045S-M3

Vishay Semiconductors

High Performance Schottky Rectifier, 6 A



PRIMARY CHARACTERISTICS					
I _{F(AV)} 6 A					
V _R	35 V, 40 V, 45 V				
V _F at I _F	0.53 V				
I _{RM}	7 mA at 125 °C				
T _J max.	175 °C				
E _{AS}	8 mJ				
Package	D ² PAK (TO-263AB)				
Circuit configuration	Single				

FEATURES

- 175 °C T_J operation
- · High frequency operation
- Low forward voltage drop
- high High purity, temperature ероху encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-6TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES UNITS								
I _{F(AV)}	Rectangular waveform	6	А					
V _{RRM}	Range	35 to 45	V					
I _{FSM}	t _p = 5 μs sine	690	А					
VF	6 A _{pk} , T _J = 125 °C	0.53	V					
TJ	Range	-55 to +175	°C					

VOLTAGE RATINGS								
PARAMETER	VS-6TQ040S-M3	VS-6TQ045S-M3	UNITS					
Maximum DC reverse voltage	V _R	35	40	45	V			
Maximum working peak reverse voltage	V _{RWM}		40	40	v			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS			
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_{C} = 164 °C	6					
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse Following any rated load 10 ms sine or 6 ms rect. pulse condition and with rated V _{RRM} applied		690	А			
non-repetitive surge current See fig. 7	I _{FSM}			140				
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1.20 A, L = 11.10 mH		8	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.20	А			

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HALOGEN

FREE

VS-6TQ035S-M3, VS-6TQ040S-M3, VS-6TQ045S-M3



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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS			
		6 A	T.ı = 25 °C	0.60	V			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	12 A	1j = 25 C	0.73				
See fig. 1	V FM	6 A	T _ 105 °C	0.53				
		12 A	T _J = 125 °C	0.64				
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C		0.8	mA			
See fig. 2	IRM ("	T _J = 125 °C	$V_R = Rated V_R$	7				
Threshold voltage	V _{F(TO)}			0.35	V			
Forward slope resistance	r _t	$T_J = T_J maximum$		18.23	mΩ			
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		400	pF			
Typical series inductance	L _S	Measured lead to lead 5 m	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs			

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to 175	°C		
Maximum thermal resistance, junction to case	,		DC operation See fig. 4	2.2	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	R _{thCS} Mounting surface, smooth, and greased		0/11		
Approvimente weight				2	g		
Approximate weight				0.07	oz.		
Mounting torque	minimum			6 (5)	kgf · cm		
Mounting torque maximum				12 (10)	(lbf · in)		
Marking device				6TQ	035S		
			Case style D ² PAK (TO-263AB)	6TQ	040S		
				6TQ	045S		

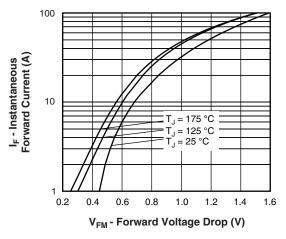
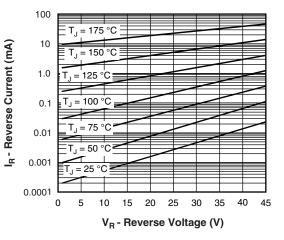
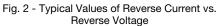


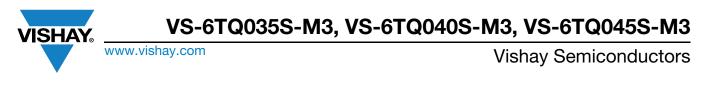
Fig. 1 - Maximum Forward Voltage Drop Characteristics





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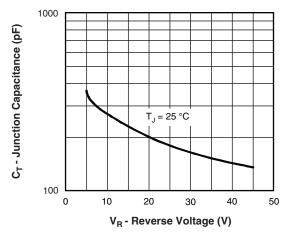


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

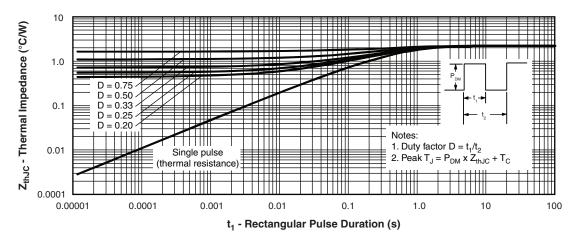


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Average Power Loss (W)

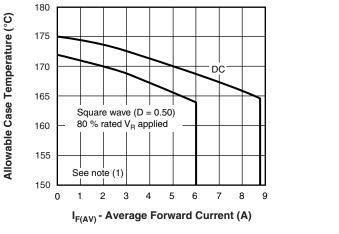


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

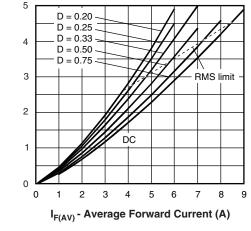


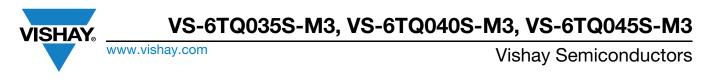
Fig. 6 - Forward Power Loss Characteristics

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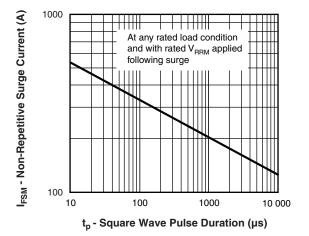


Fig. 7 - Maximum Non-Repetitive Surge Current

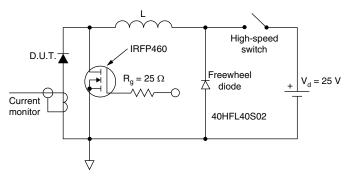


Fig. 8 - Unclamped Inductive Test Circuit

Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
 - $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

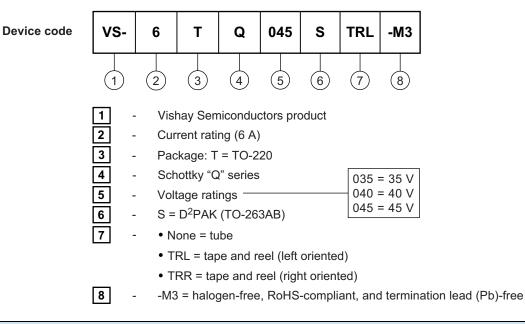
VS-6TQ035S-M3, VS-6TQ040S-M3, VS-6TQ045S-M3

Vishay Semiconductors

ORDERING INFORMATION TABLE

www.vishay.com

SHAY



ORDERING INFORMATION									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-6TQ035S-M3	50	1000	Antistatic plastic tubes						
VS-6TQ035STRR-M3	800	800	13" diameter reel						
VS-6TQ035STRL-M3	800	800	13" diameter reel						
VS-6TQ040S-M3	50	1000	Antistatic plastic tubes						
VS-6TQ040STRR-M3	800	800	13" diameter reel						
VS-6TQ040STRL-M3	800	800	13" diameter reel						
VS-6TQ045S-M3	50	1000	Antistatic plastic tubes						
VS-6TQ045STRR-M3	800	800	13" diameter reel						
VS-6TQ045STRL-M3	800	800	13" diameter reel						

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96164				
Part marking information	www.vishay.com/doc?95444				
Packaging information	www.vishay.com/doc?96424				

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D²PAK

DIMENSIONS in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STNDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 13-Jul-17

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Document Number: 96164

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